



Attorney Docket No.: 5649-1129



FFW

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re: Yun et al.  
Serial No.: 10/629,280  
Filed: July 29, 2003  
For: GATE STRUCTURES IN NONVOLATILE MEMORY DEVICES HAVING  
CURVED SIDEWALLS FORMED USING OXYGEN PATHWAYS

Group Art Unit: 2818  
Examiner: Thao P. Le  
Confirmation No.: 5702

November 23, 2004

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**AMENDMENT**

Sir:

Applicants provide the present Amendment to address the issues raised in the Official Action mailed September 2, 2004, pursuant to the rules stated in revised 37 C.F.R. 1.121 that became effective on July 30, 2003.

It is not believed that an extension of time and/or additional fee(s), including fees for additional claims, are required, beyond those that may otherwise be provided for in documents accompanying this paper. In the event, however, that an extension of time is necessary to allow consideration of this paper, such an extension is hereby petitioned under 37 C.F.R. §1.136(a). Any additional fees believed to be due in connection with this paper may be charged to our Deposit Account No. 50-0220.

**Amendment to the Title** is reflected on Page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims, which begin on page 3 of this paper.

**Remarks/Arguments** begin on page 8 of this paper.

**In the Title:**

Please replace all occurrences of the Title with the following amended Title:

**METHODS OF FORMING GATE STRUCTURES IN NONVOLATILE MEMORY**  
**DEVICES HAVING CURVED SIDEWALLS FORMED USING OXYGEN**  
**PATHWAYS AND METHODS OF FORMING SAME**